CH$_3$NH$_3$PbI$_3$ Perovskite Solar Cells Employing Cu-Phthalocyanine Doped Poly-3-hexylthiophene Hole-Transporting Layer

Vincent Obiozo Eze, Yoshiyuki Seike and Tatsuo Mori*

Department of Electrical and Electronics Engineering, Aichi Institute of Technology, Aichi, 470-0392 Japan.
E-mail: t2mori@aitech.ac.jp*

Introduction
Organic-inorganic perovskite solar cells (PSCs) have recently emerged at the forefront of photovoltaics research. Over the past six years, the power conversion efficiencies (PCEs) have rapidly increased from 3.8% in 2009 to approximately 20% in 2015. Herein, we report the use of hydrophobic poly (3-hexylthiophene) (P3HT) Hole transport layer (HTL) to prevent moisture ingress into the perovskite layer. Cu-phthalocyanine (CuPc) chlorobenzene suspension is introduced as a dopant for enhancing charge extraction. CuPc is thermally and chemically very stable material, and by mixing with a P3HT solution, the aggregation of CuPc nanoparticles was suppressed. Interestingly, the incorporation of the CuPc into P3HT solution led to the significant enhancement of the PSCs’ efficiency from 7.90% to 10.10%.

Results and Discussion
Mesoscopic PSCs were fabricated with the structure fluorine-doped tin oxide (FTO)/compact-TiO$_2$/MAPbI$_3$/P3HT:CuPc/Au in ambient air. Figure 1 presents the solar cell configuration and scanning electron microscope (SEM) cross-sectional image of the device. The light and dark current density–voltage (J–V) curves of the best performance devices measured under simulated 1.5G solar irradiation at 100 mW/cm$^2$ is shown in Fig. 2. The short-circuit current density ($I_{sc}$) of 20.00 mA/cm$^2$, an open-circuit voltage ($V_{oc}$) of 0.840 V, a fill factor (FF) of 0.470 and PCE of 7.90% were obtained from the pristine P3HT device. While the optimized device with P3HT: CuPc as HTL shows a $I_{sc}$ of 21.40, $V_{oc}$ of 0.870, and FF of 0.541 leading to a PCE of 10.10%.

Fig. 1. Device architecture and SEM cross-section image of PSCs.

Fig. 2 (a) J–V curves of P3HT and P3HT:CuPc PSCs. (b) dark J–V of P3HT and P3HT:CuPc PSCs.

The improved photovoltaic performance obtained by the P3HT:CuPc device could be attributed to the suppressed leakage current and charge recombination due to an efficient hole transporting and electron blocking as shown in Fig. 2 (b)

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References
(2) Vincent Obiozo Eze et al., 2016 Jpn. J. Appl. Phys. 55 02BF08